

Product Summary

| V_{RRM} (V) | I_O (A) | V_F MAX (V) @+25°C | I_R MAX (mA) @+25°C |
|---------------|-----------|----------------------|-----------------------|
| 45 | 10 | 0.58 | 0.3 |

Description and Applications


This Super Barrier Rectifier (SBR) diode has been designed to meet the stringent requirements of Automotive Applications. It is ideally suited to use as :

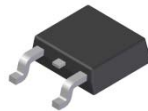
- Polarity Protection Diode
- Re-circulating Diode
- Switching Diode

Features

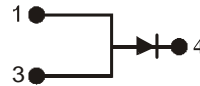
- 100% Avalanche Tested.
- Patented SBR technology provides a superior avalanche capability than schottky diodes ensuring more rugged and reliable end applications.
- Reduced ultra-low forward voltage drop (VF); better efficiency and cooler operation.
- Reduced high temperature reverse leakage; increased reliability against thermal runaway failure at high temperature
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 
- Weight: 0.33 grams (approximate)



Top View



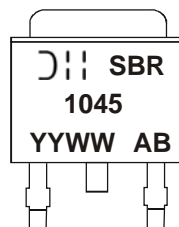
Polarity

Ordering Information (Note 4)

| Part Number | Compliance | Case | Packaging |
|---------------|------------|--------------|------------------|
| SBR1045D1Q-13 | Automotive | TO252 (DPAK) | 2500/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



SBR1045 = Product Type Marking Code
 AB = Foundry and Assembly Code
 YYWW = Date Code Marking
 YY = Last two digits of year (ex: 13 = 2013)
 WW = Week (01 - 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitance load, derate current by 20%.

| Characteristic | Symbol | Value | Unit |
|---|---------------------|-------|------|
| Peak Repetitive Reverse Voltage | V _{RRM} | 45 | V |
| Working Peak Reverse Voltage | V _{RWM} | | |
| DC Blocking Voltage | V _{RM} | | |
| RMS Reverse Voltage | V _{R(RMS)} | 32 | V |
| Average Rectified Output Current | I _O | 10 | A |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load | I _{FSM} | 90 | A |
| Repetitive Peak Avalanche Power (1μs, +25°C) | P _{ARM} | 5000 | W |
| Non-Repetitive Avalanche Energy (T _J = +25°C, I _{AS} = 12A, L = 10mH) | E _{AS} | 200 | mJ |

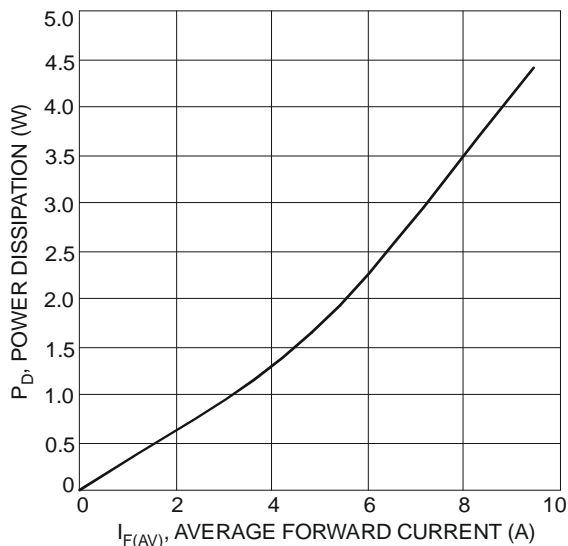
Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|---|--------------------------------------|-------------|------|
| Typical Thermal Resistance | R _{θJA} R _{θJC} | 29 | °C/W |
| Thermal Resistance Junction to Ambient (Note 5) | | 3 | |
| Thermal Resistance Junction to Case (Note 5) | | | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

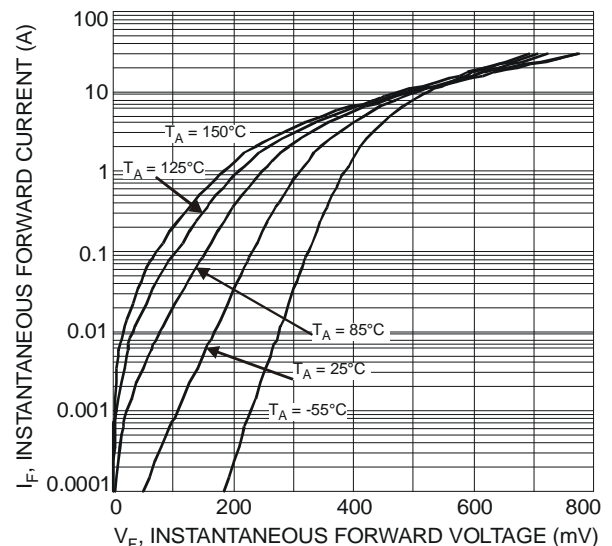
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|------------------------------------|--------------------|-----|------|------|------|---|
| Reverse Breakdown Voltage (Note 6) | V _{(BR)R} | 45 | — | — | V | I _R = 0.5mA |
| Forward Voltage Drop | V _F | — | 0.42 | — | V | I _F = 5A, T _J = +25°C |
| | | — | 0.37 | — | | I _F = 5A, T _J = +125°C |
| | | — | 0.53 | 0.58 | | I _F = 10A, T _J = +25°C |
| | | — | 0.50 | — | | I _F = 10A, T _J = +125°C |
| Leakage Current (Note 6) | I _R | — | 150 | 300 | μA | V _R = 45V, T _J = +25°C |
| | | — | 50 | — | mA | V _R = 45V, T _J = +125°C |
| Total Capacitance | C _T | — | 400 | — | pF | V _R = 5V, f = 1MHz T _J = +25°C |

Notes: 5. Device mounted on polyimide substrate, 240mm² Copper pad, double-sided PC Board.
 6. Short duration pulse test used to minimize self-heating effect.



Notes: 7. Polyimide, 2oz. Copper 16x minimum recommended pad layout per <http://www.diodes.com>



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SBR1045D1Q

Document number: DS36362 Rev. 1 - 2

2 of 5
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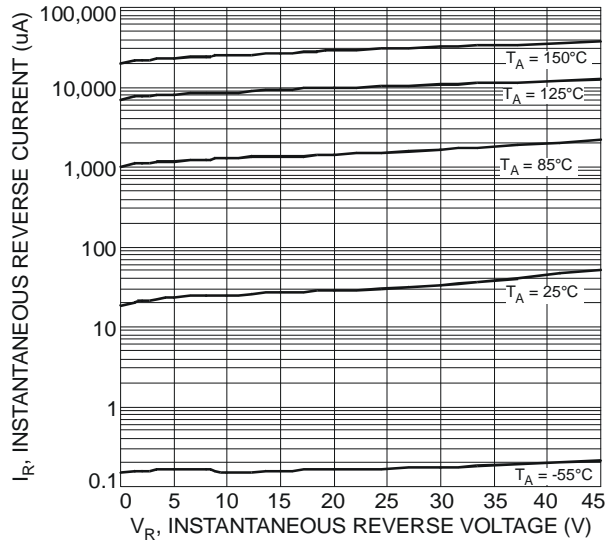


Fig. 3 Typical Reverse Characteristics

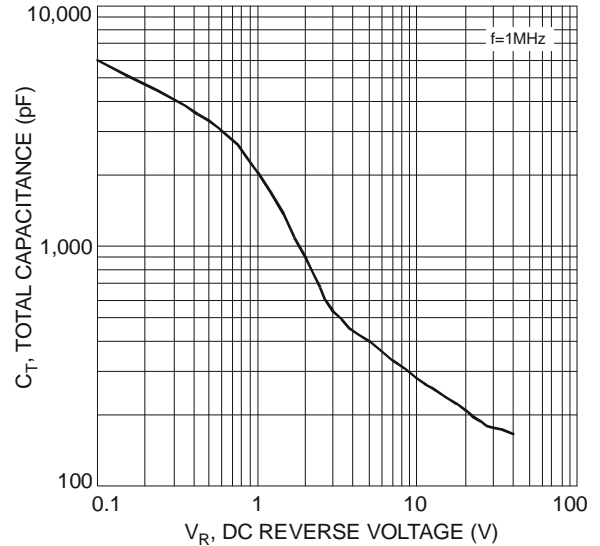


Fig. 4 Total Capacitance vs. Reverse Voltage

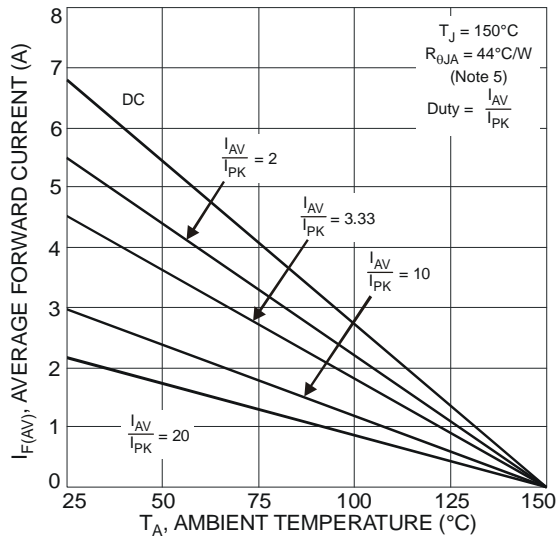


Fig. 5 Forward Current Derating Curve

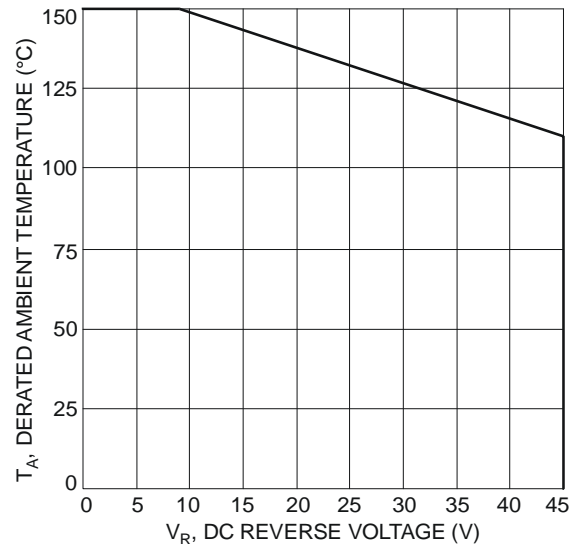


Fig. 6 Operating Temperature Derating

Notes: 8. Polyimide, 2oz. Copper 16x minimum recommended pad layout per <http://www.diodes.com>

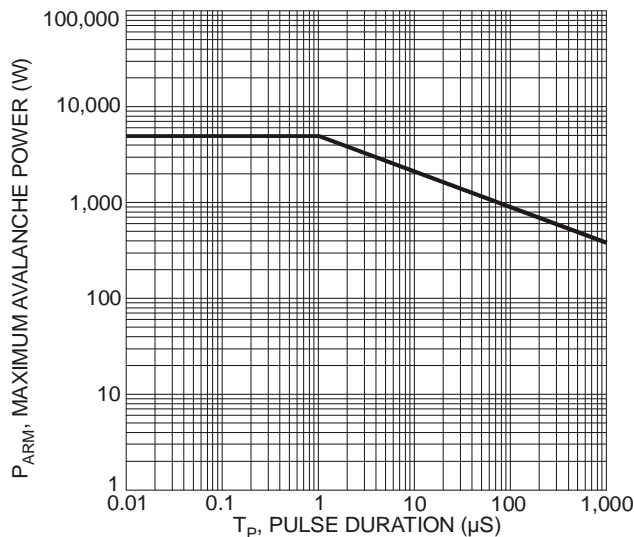


Fig. 7 Maximum Avalanche Power Curve

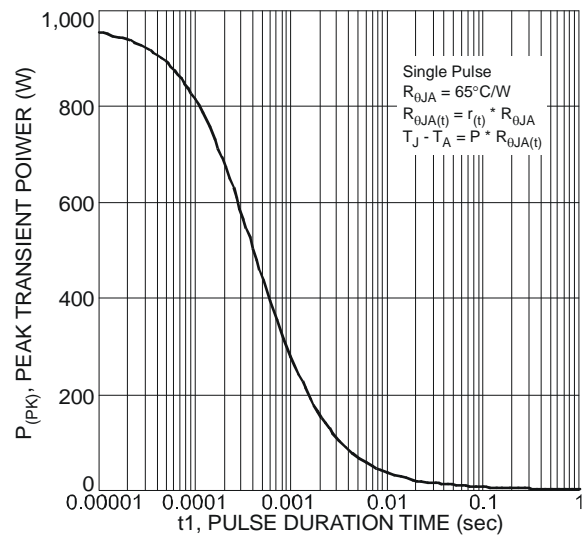
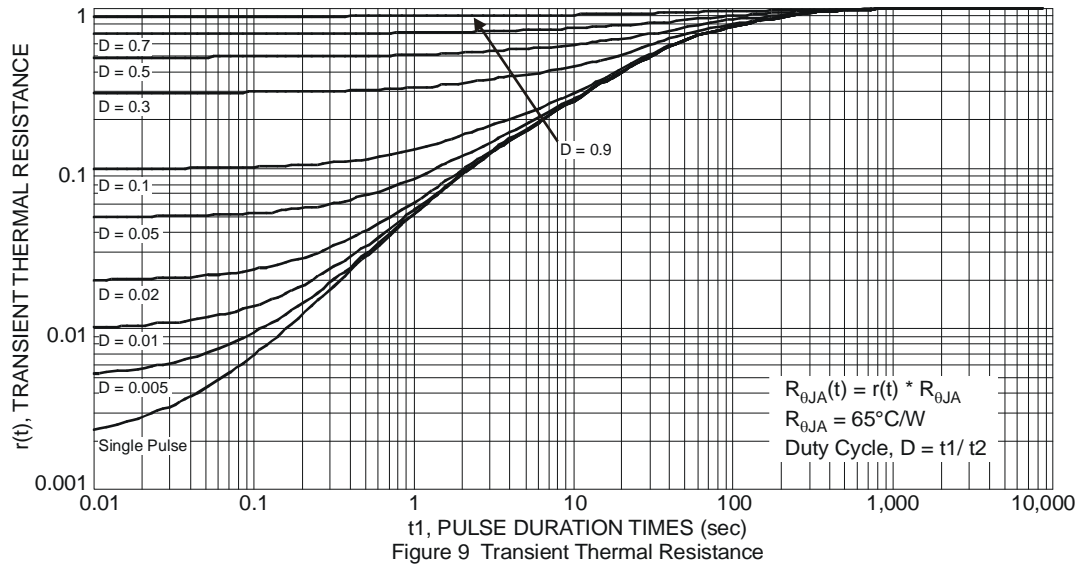
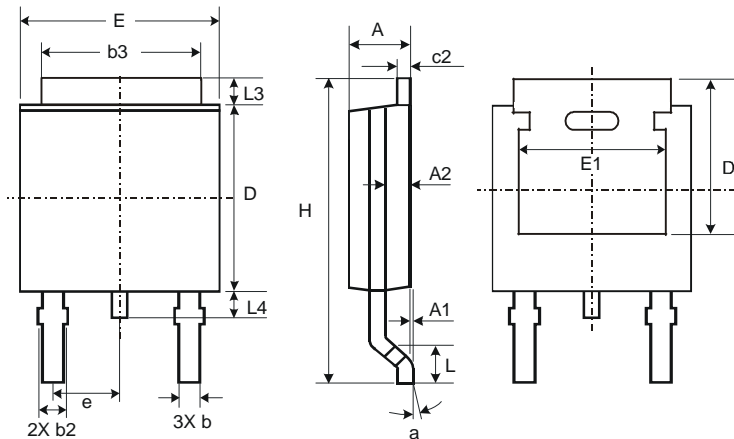


Figure 8 Single Pulse Maximum Power Dissipation



Package Outline Dimensions

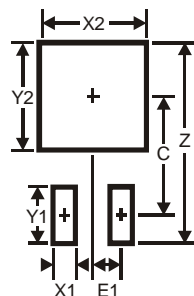
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| TO252 | | | |
|----------------------|------|-------|-------|
| Dim | Min | Max | Typ |
| A | 2.19 | 2.39 | 2.29 |
| A1 | 0.00 | 0.13 | 0.08 |
| A2 | 0.97 | 1.17 | 1.07 |
| b | 0.64 | 0.88 | 0.783 |
| b2 | 0.76 | 1.14 | 0.95 |
| b3 | 5.21 | 5.46 | 5.33 |
| c2 | 0.45 | 0.58 | 0.531 |
| D | 6.00 | 6.20 | 6.10 |
| D1 | 5.21 | — | — |
| e | — | — | 2.286 |
| E | 6.45 | 6.70 | 6.58 |
| E1 | 4.32 | — | — |
| H | 9.40 | 10.41 | 9.91 |
| L | 1.40 | 1.78 | 1.59 |
| L3 | 0.88 | 1.27 | 1.08 |
| L4 | 0.64 | 1.02 | 0.83 |
| a | 0° | 10° | — |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 11.6 |
| X1 | 1.5 |
| X2 | 7.0 |
| Y1 | 2.5 |
| Y2 | 7.0 |
| C | 6.9 |
| E1 | 2.3 |

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